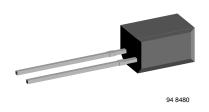
Vishay Semiconductors

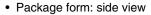


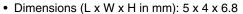
Silicon PIN Photodiode, RoHS Compliant



FEATURES

· Package type: leaded





• Radiant sensitive area (in mm²): 7.5

· High radiant sensitivity

· Daylight blocking filter matched with 870 nm to 950 nm emitters

- · Fast response times
- Angle of half sensitivity: $\varphi = \pm 65^{\circ}$
- (Pb)-free component in accordance RoHS 2002/95/EC and WEEE 2002/96/EC



- · High speed detector for infrared radiation
- Infrared remote control and free air data transmission systems, e.g. in combination with TSFFxxxx series IR emitters

DESCRIPTION

BPW82 is a PIN photodiode with high speed and high radiant sensitivity in a black, side view plastic package with daylight blocking filter. Filter bandwidth is matched with 870 nm to 950 nm IR emitters.

PRODUCT SUMMARY				
COMPONENT	I _{ra} (μΑ)	φ (deg)	λ _{0.5} (nm)	
BPW82	45	± 65	790 to 1050	

Test condition see table "Basic Characteristics"

ORDERING INFORMATION				
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
BPW82	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	Side view	

Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V _R	60	V	
Power dissipation	T _{amb} ≤ 25 °C	P _V	215	mW	
Junction temperature		T _j	100	°C	
Operating temperature range		T _{amb}	- 40 to + 100	°C	
Storage temperature range		T _{stg}	- 40 to + 100	°C	
Soldering temperature	t ≤ 5 s	T _{sd}	260	°C	
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm ²	R _{thJA}	350	K/W	

 T_{amb} = 25 °C, unless otherwise specified











Silicon PIN Photodiode, RoHS Compliant Vishay Semiconductors

BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Breakdown voltage	I _R = 100 μA, E = 0	V _(BR)	60			V
Reverse dark current	V _R = 10 V, E = 0	I _{ro}		2	30	nA
Diode capacitance	$V_R = 0 V, f = 1 MHz, E = 0$	C_D		70		pF
	V _R = 3 V, f = 1 MHz, E = 0	C _D		25	40	pF
Open circuit voltage	$E_e = 1 \text{ mW/cm}^2, \lambda = 870 \text{ nm}$	Vo		350		mV
Short circuit current	$E_e = 1 \text{ mW/cm}^2, \lambda = 870 \text{ nm}$	l _k		38		μΑ
Reverse light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 870 \text{ nm}, $ $V_R = 5 \text{ V}$	I _{ra}	43	45		μΑ
Angle of half sensitivity		φ		± 65		deg
Wavelength of peak sensitivity		λ_{p}		950		nm
Range of spectral bandwidth		λ _{0.5}		790 to 1050		nm
Noise equivalent power	V _R = 10 V, λ = 870 nm	NEP		4 x 10 ⁻¹⁴		W/√Hz
Rise time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t _r		100		ns
Fall time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t _f		100		ns

Note

T_{amb} = 25 °C, unless otherwise specified

BASIC CHARACTERISTICS

 T_{amb} = 25 °C, unless otherwise specified

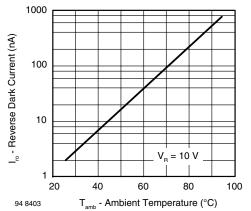


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

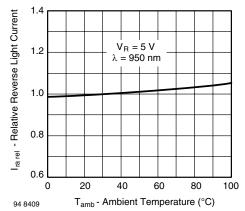


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

Silicon PIN Photodiode, RoHS Compliant



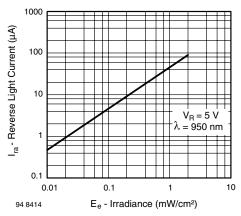


Fig. 3 - Reverse Light Current vs. Irradiance

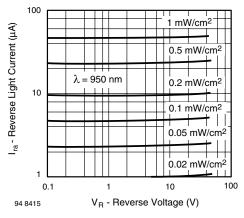


Fig. 4 - Reverse Light Current vs. Reverse Voltage

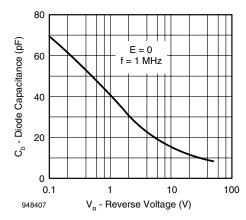


Fig. 5 - Diode Capacitance vs. Reverse Voltage

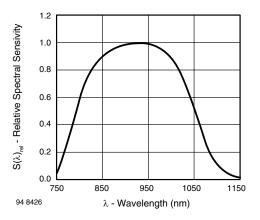


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

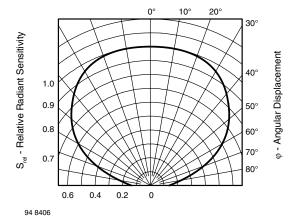
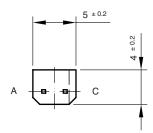


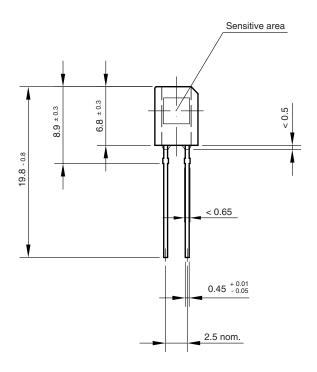
Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

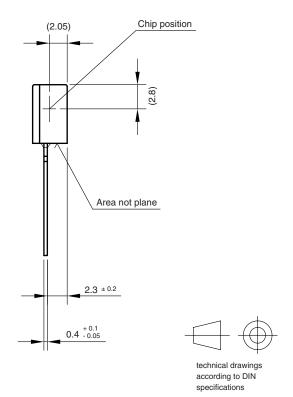


Silicon PIN Photodiode, RoHS Compliant Vishay Semiconductors

PACKAGE DIMENSIONS in millimeters







Drawing-No.: 6.544-5108.01-4

Issue:1; 01.07.96

96 12195



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Revision: 02-Oct-12 Document Number: 91000

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